Vertical Cavity Surface Emitting Laser in FC Optical Sub-Assembly

OPV315AT, OPV315YBT



Features:

- 850 nm VCSEL technology
- High thermal stability
- Up to 2.5 Gbps
- Recommended for multimode fiber applications
- Microbead lens
- Pin out and attenuation options available upon request
- Burned in for communication level reliability
- High optical coupling to MM fiber
- ST style receptacle



Description:

The OPV315AT is a high performance 850nm VCSEL packaged for high speed communication links. OPV315AT combines all the performance advantages of a VCSEL with the addition of a power monitor diode for precise control of optical power.

The OPV314YBT is identical electrically and optically and differ only in pin out. Refer to mechanical drawings for details.

This product's combination of features including high speed, high output power and concentric beam makes it an ideal transmitter for integration into all types of data communications equipment.

Applications:

- Fiber channel
- Gigabit Ethernet
- ATM
- VSR (very short reach)
- Intra-system links applications
- · Optical backplane interconnects

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature	-40° C to +125° C
Operating Temperature	0° C to +85° C
Soldering Lead Temperature	260° C for 10 Seconds
Maximum Forward Peak Current, Continuous	12 mA
Maximum Reverse Voltage	5 V
Maximum Forward Current, pulsed 1µs P.W., 10% D.C.)	48mA



Additional laser safety information can be found on the Optek website. See application #221. Classification is not marked on the device due to space limitations. See package outline for centerline of optical radiance. Operating devices beyond maximum rating may cause devices to exceed rated classification





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Electrical Specifications

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
P _{T50}	Total coupled power OPV315AT 50/125 μm fiber OPV315YBT	300			μW	I _F = 7 mA
		200			μW	I _F = 7 mA
I _{TH}	Threshold current	0.8		3.0	mA	Note 1
V _F	Forward voltage	1.6		2.2	V	I _F = 7 mA
I _R	Reverse current			100	nA	V _R = 5 V
R_{S}	Series resistance	20		55	Ohms	Note 2
η	Slope efficiency OPV315AT OPV315YBT	30			μW/mA	Note 3
		20			μW/mA	
I _{RPD}	Reverse current, photodiode			35	nA	V _R = 40 V
I _M	Monitor current	30			μΑ	I _F = 7 mA, V _R = 5 V
	Linearity	0.00				Note 4
λ	Wavelength	840		860	Nm	
Δλ	Optical bandwidth			0.85	Nm	
t _r	Rise time		90		Ps	20 to 80%
t _f	Fall time		120		Ps	80 to 20%
N _{RI}	Relatively intensity noise		-123		Db/Hz	
Δη/ΔΤ	Temp coefficient of slope efficiency		-0.5		%/°C	0° - 70°C
ΔI_{TH}	Temp variance of threshold current		±1.0		mA	0° - 70°C
Δλ/ΔΤ	Temp coefficient of wavelength		0.06		Nm/°C	0° - 70°C
$\Delta V_f/\Delta T$	Temperature coefficient for V _F		-2.5		Mv/°C	

NOTES:

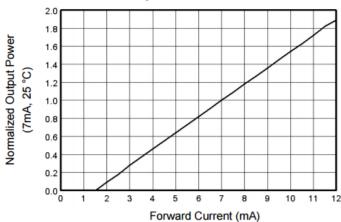
- (1) Threshold Current is based on the two line intersection method specified in Telcordia GR-468-Core. Line 1 from 4 mA to 6 mA. Line 2 from 0 mA to 0.5 mA.
- (2) Series Resistance is the slope of the Voltage-Current line from 5 to 8 mA.
- (3) Slope efficiency, is the slope of the best fit LI line from 5 mA to 8 mA using no larger than .25 mA test interval points. Measured with a 50/125 μm fiber.
- (4) Linearity—Using data points taken for slope efficiency above, data L/delta I shall be calculated for each adjacent pair of points.

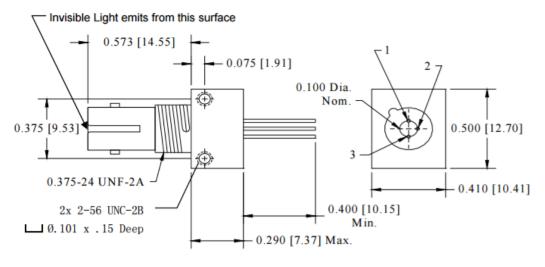
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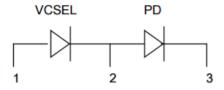
OPV315AT, OPV315YBT



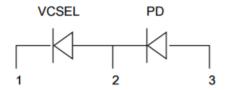
Normalized Output Power vs. Forward Current







OPV315AT, OPV315BT				
Pin	Connection			
1	VCSEL Anode			
2	VCSEL Cathode/PD Anode			
3	PD Cathode			



OPV315YAT, OPV315YBT				
Pin	Connection			
1	VCSEL Cathode			
2	VCSEL Anode/PD Cathode			
3	PD Anode			

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.